

RN1427TE85LF Information


For Reference Only

Part Number [RN1427TE85LF](#)
Manufacturer Toshiba Semiconductor and Storage
Category Discrete Semiconductor Products
[Transistors - Bipolar \(BJT\) - Single, Pre-Biased](#)
Description TRANS PREBIAS NPN 200MW SMINI
Package TO-236-3, SC-59, SOT-23-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


RN1427TE85LF Specifications

Manufacturer Part Number	RN1427TE85LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	800mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	2.2k
Resistor - Emitter Base (R2) (Ohms)	10k
DC Current Gain (hFE) (Min) @ Ic, Vce	90 @ 100mA, 1V
Vce Saturation (Max) @ Ib, Ic	250mV @ 1mA, 50mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	300MHz
Power - Max	200mW
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	S-Mini

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RN1427TE85LF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1427TE85LF Payment Methods



RN1427TE85LF Shipping Methods



If you have any question about RN1427TE85LF, please do not hesitate to contact us!

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